

Product Summary

BV _{DSS}	Rds(on) Max	Q _g Typ	ID Tc = +25°C (Note 7)
40V	2.7mΩ @ V _{GS} = 10V	68.6nC	100A

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

Applications

- Engine management systems
- Body control electronics
- DC-DC converters

Features

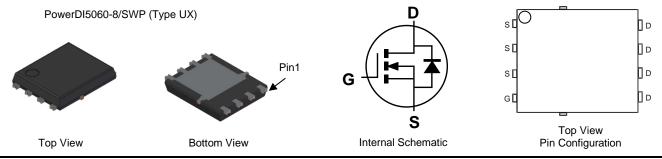
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low RDS(ON) Minimizes Power Losses
- Low Qg Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

 An automotive-compliant part is available under separate datasheet (<u>DMTH4004SPSWQ</u>)

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

Ordership Bart Number	Baakaga	Packing		
Orderable Part Number	Package	Qty.	Carrier	
DMTH4004SPSW-13	PowerDI5060-8/SWP (Type UX)	2500	Tape & Reel	

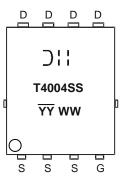
EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

<1000ppm antimony compounds. 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



 \bigcirc = Manufacturer's Marking T4004SS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 24 = 2024) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	40	V	
Gate-Source Voltage	Vgss	±20	V	
Continuous Drain Current (Note 5)	T _A = +25°C T _A = +70°C	ID	31 26	A
Continuous Drain Current (Note 6)	T _C = +25°C (Note 7) T _C = +100°C	ID	100	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	<u> 100</u> 350	A	
Maximum Continuous Body Diode Forward Current (Note 5)	ls	100	A	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle :	lsм	350	A	
Avalanche Current, L = 0.2mH	I _{AS}	45	A	
Avalanche Energy, L = 0.2mH		Eas	200	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	3.6	W
Thermal Resistance, Junction to Ambient (Note 5)	Reja	41	°C/W	
Total Power Dissipation (Note 6) $T_{C} = +25^{\circ}C$		PD	167	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	0.9	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BVDSS	40	—	—	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	_	—	1	μA	$V_{DS} = 32V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	2	—	4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)	_	2.3	2.7	mΩ	VGS = 10V, ID = 90A	
Diode Forward Voltage	Vsd	—	0.9	1.2	V	VGS = 0V, IS = 20A	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	_	4,305	_	pF	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss	—	1,441	—			
Reverse Transfer Capacitance	Crss	—	102	—			
Gate Resistance	Rg	—	0.77	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	68.6	_		$V_{DD} = 20V, I_D = 90A,$	
Gate-Source Charge	Qgs	_	16.8	_	nC		
Gate-Drain Charge	Q _{gd}	_	14.2	_		Vgs = 10V	
Turn-On Delay Time	td(on)	_	9.5	_		$V_{DD} = 20V, V_{GS} = 10V,$ $I_D = 90A, R_G = 3.5\Omega$	
Turn-On Rise Time	t _R	_	6.7	_			
Turn-Off Delay Time	t _{D(OFF)}	_	26.4		ns		
Turn-Off Fall Time	tF	_	8.1				
Body Diode Reverse Recovery Time	trr		52.4		ns		
Body Diode Reverse Recovery Charge	Qrr	_	78.2		nC	IF = 50A, di/dt = 100A/µs	

5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

6. Thermal resistance from junction to soldering point (on the exposed drain pad).

7. Package limited.

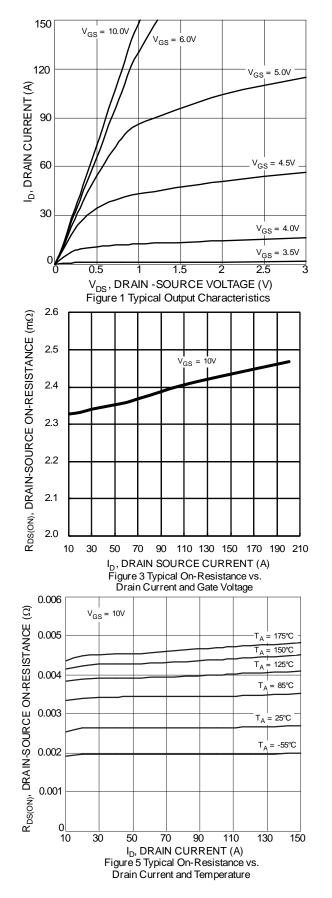
Notes:

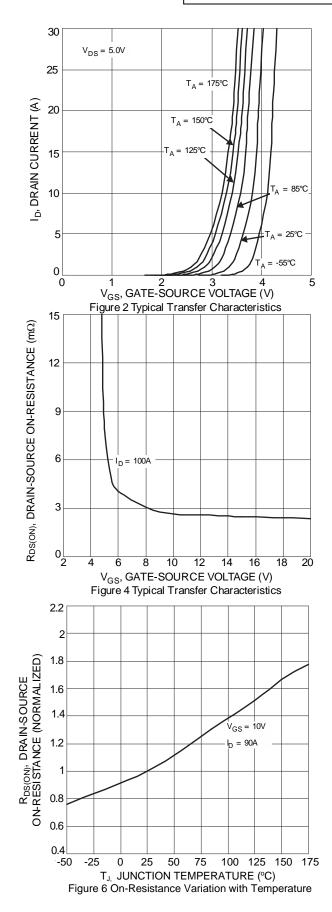
8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to production testing.



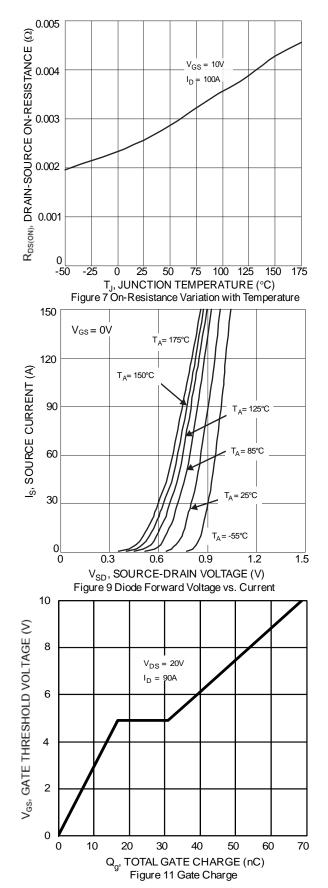
DMTH4004SPSW

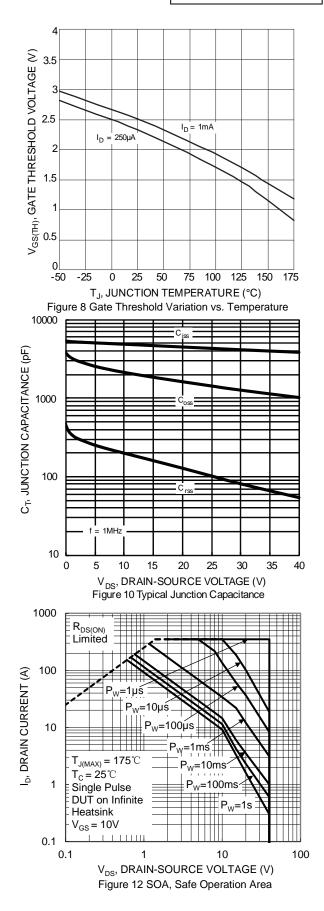




DMTH4004SPSW Document number: DS46751 Rev. 1 - 2

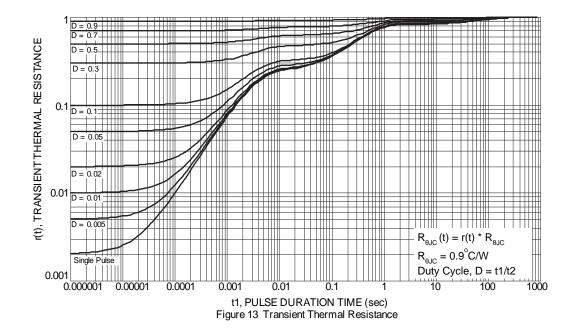






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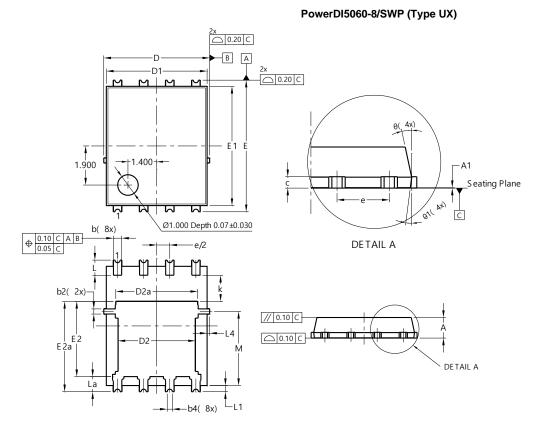






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

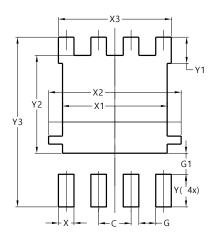


Po	PowerDI5060-8/SWP (Type UX)				
Dim	Min	Max	Тур		
A	0.90	1.10	1.00		
A1	0	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4	().25REF	-		
С	0.230	0.330	0.277		
D	5	.15 BS0	0		
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78 4.18 3.98				
Е		.40 BS0	2		
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1	.27BSC)		
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L4	0.025	0.225	0.125		
М	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	5.190		
X3	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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